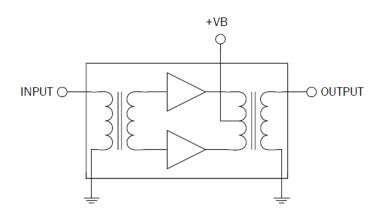


D10040270GT

GaAs Power Doubler Hybrid 40MHz to 1000MHz

The D10040270GT is a Hybrid Power Doubler amplifier module. The part employs GaAs die and is operated from 40MHz to 1000MHz. It provides excellent linearity and superior return loss performance with low noise and optimal reliability.



Ordering Information

D10040270GT Box with 50 pieces

Absolute Maximum Ratings

Parameter	Rating	Unit
RF Input Voltage (single tone)	75	dBmV
DC Supply Over-Voltage (5 minutes)	30	V
Storage Temperature	-40 to +100	°C
Operating Mounting Base Temperature	-30 to +100	°C



Package: SOT-115J

Features

- Excellent Linearity
- Superior Return Loss Performance
- Extremely Low Distortion
- Optimal Reliability
- Low Noise
- Unconditionally Stable Under All Terminations
- 27.0dB Min. Gain at 1GHz
- 375mA Max. at 24VDC

Applications

 40MHz to 1000MHz CATV Amplifier Systems



RoHS

Caution! ESD sensitive device.

RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2011/65/EU.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implie

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Nominal Operating Parameters

Parameter	Specification		Unit	Condition	
	Min	Тур	Max	Unit	Condition
General Performance					V+ = 24V; T _{MB} = 30°C; Z _S = Z _L = 75Ω
Power Gain	26.0	26.5	27.0	dB	f = 50MHz
	27.0	28.0	28.5	dB	f = 1000MHz
Slope ^[1]	0.5	1.5	2.0	dB	f = 40MHz to 1000MHz
Flatness of Frequency Response			0.8	dB	f = 40MHz to 1000MHz (Peak to Valley)
Input Return Loss	20.0			dB	f = 40MHz to 320MHz
	19.0			dB	f = 320MHz to 640MHz
	17.0			dB	f = 640MHz to 870MHz
	16.0			dB	f = 870MHz to 1000MHz
Output Return Loss	20.0			dB	f = 40MHz to 320MHz
	19.0			dB	f = 320MHz to 640MHz
	18.0			dB	f = 640MHz to 870MHz
	17.0			dB	f = 870MHz to 1000MHz
Noise Figure		4.5	5.0	dB	f = 50MHz to 1000MHz
Total Current Consumption (DC)		360.0	375.0	mA	
Distortion Data 40MHz to 870MHz					$V_{+} = 24V; T_{MB} = 30^{\circ}C; Z_{S} = Z_{L} = 75\Omega$
СТВ		-64	-62	dBc	
XMOD		-60	-58	dBc	132 ch flat; $V_0 = 44 dBm V^{[2]}$
CSO		-65	-63	dBc	

1. The slope is defined as the difference between the gain at the start frequency and the gain at the stop frequency.

2. 132 channels, NTSC frequency raster: 55.25MHz to 865.25MHz, +44dBmV flat output level.

Composite Second Order (CSO) - The CSO parameter (both sum and difference products) is defined by the NCTA.

Composite Triple Beat (CTB) - The CTB parameter is defined by the NCTA.

Cross Modulation (XMOD) - Cross modulation (XMOD) is measured at baseband (selective voltmeter method), referenced to 100% modulation of the carrier being tested.